Diode Semiconductor Device - Page 1 of 1



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Inclosur	e Material:
Glass an	d metal
Overall L	Length:
1.000 inc	ches
Overall [Diameter:
1.000 inc	ches
Mountin	g Facility Quantity:
1	
Joint Ele	ectronic Device Engineering Council/jedec/case Outline Designation
Do-8	
Mountin	g Method:
Threaded	d stud
Features	s Provided:
Hermetic	cally sealed case
Overall \	Width Across Flats:
1.062 inc	ches
Thread S	Size:
0.375 inc	ches
Semicor	nductor Material:
Silicon	
Voltage	Rating In Volts Per Characteristic:
200.0 re	verse voltage, peak
Current	Rating Per Characteristic:
100.00 a	mperes forward current, average absolute
Maximu	m Operating Tempurature Per Measurement Point:
200.0 de	grees celsius case
Thread S	Series Designator:
Unf	
Termina	I Type And Quantity:
1 threade	ed stud and 1 tab, solder lug
Shelf Lif	e:
N/a	
Unit Of M	Measure:
Demilita	rization:
No	
Fiig:	
A110a0	